



### 60V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> T <sub>C</sub> = +25°C
60V	5.6mΩ @ V <sub>GS</sub> = 10V	90A

## **Description and Applications**

This MOSFET has been designed to meet the stringent requirements of Automotive applications. It is qualified to AECQ101, supported by a PPAP and is ideal for use in:

- Engine Management Systems
- Body Control Electronics
- DCDC Converters

### **Features**

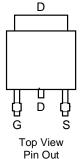
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching ensures more reliable and robust end application
- Low R<sub>DS(ON)</sub> minimizes power losses
- Low Q<sub>q</sub> minimizes switching losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

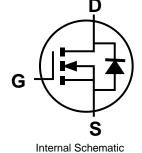
#### **Mechanical Data**

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 <sup>©3</sup>
- Weight: 0.33 grams (Approximate)









### Ordering Information (Note 5)

Part Number	Case	Packaging
DMTH6005LK3Q-13	TO252 (DPAK)	2,500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product\_compliance\_definitions.html
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html

## **Marking Information**



OII = Manufacturer's Marking
H6005L = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 15 = 2015)
WW = Week Code (01 to 53)



## **Maximum Ratings** (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Drain-Source Voltage	$V_{DSS}$	60	V	
Gate-Source Voltage	$V_{GSS}$	±20	V	
Continuous Drain Current (Note 7)	T <sub>C</sub> = +25°C (Note 10)	ΙD	90	А
, ,	$T_{C} = +100^{\circ}C$	J	70	
Maximum Body Diode Forward Current (Note 7)	Is	90	Α	
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I <sub>DM</sub>	150	Α	
Avalanche Current, L=1mH	I <sub>AS</sub>	14.8	Α	
Avalanche Energy, L=1mH	E <sub>AS</sub>	98	mJ	

## **Thermal Characteristics**

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 6)	$T_A = +25$ °C	$P_{D}$	2.1	W
Thermal Resistance, Junction to Ambient (Note 6)		$R_{ heta JA}$	38	°C/W
Total Power Dissipation (Note 7)	$T_C = +25$ °C	$P_{D}$	100	W
Thermal Resistance, Junction to Case (Note 7)		$R_{ heta JC}$	1.5	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +175	°C

# **Electrical Character** istics ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	_	_	V	$V_{GS} = 0V$ , $I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	_	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
	<u> </u>		$V_{GS} = 10V, I_D = 50A$				
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	5.6	7.2	mΩ	$V_{GS} = 6V, I_D = 20A$	
	, ,	_	7.9	10		V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 12.5A	
Diode Forward Voltage	$V_{SD}$	_	_	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C <sub>iss</sub>	_	2962	_		V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V, f = 1MHz	
Output Capacitance	Coss	_	965.2	_	pF		
Reverse Transfer Capacitance	C <sub>rss</sub>	_	59.8	_			
Gate Resistance	R <sub>G</sub>	_	0.66	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	47.1	_			
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qq	_	23.1	_		V 00V I 50A	
Gate-Source Charge	Q <sub>gs</sub>		10.2	_	nC	$V_{DD} = 30V, I_D = 50A$	
Gate-Drain Charge	$Q_{gd}$	_	12.5	_			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	8.3	_		$V_{DD} = 30V, V_{GS} = 10V,$ $I_{D} = 30A, R_{G} = 3.3\Omega$	
Turn-On Rise Time	t <sub>R</sub>	_	9.4	_			
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	22	_	ns		
Turn-Off Fall Time	t <sub>F</sub>	_	8.9	_			
Body Diode Reverse Recovery Time	t <sub>RR</sub>	_	40.4	_	ns	1 200 4:/44 4000///-	
Body Diode Reverse Recovery Charge	$Q_{RR}$	_	49.7	_	nC	I <sub>F</sub> = 30A, di/dt = 100A/μs	

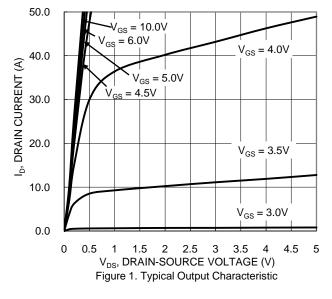
Notes: 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.

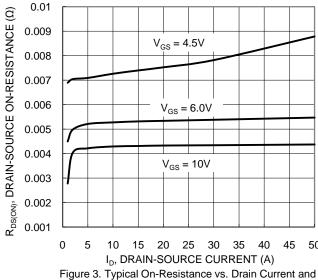
7. Thermal resistance from junction to soldering point (on the exposed drain pad).8. Short duration pulse test used to minimize self-heating effect.

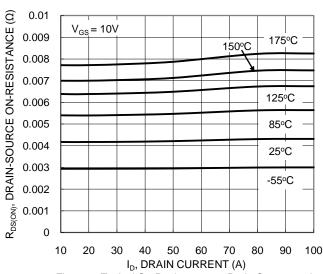
9. Guaranteed by design. Not subject to production testing.

10. Package limited.



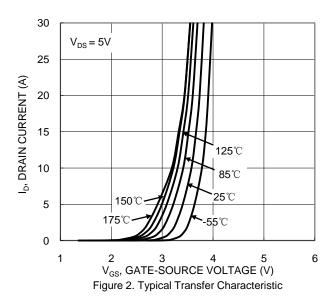


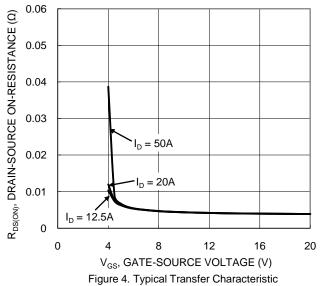




Gate Voltage

Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature





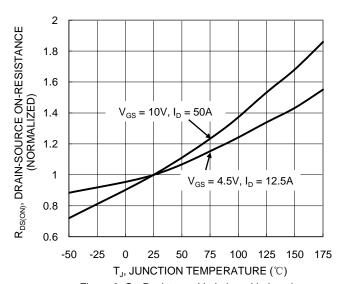
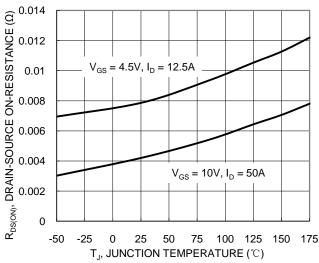
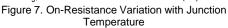


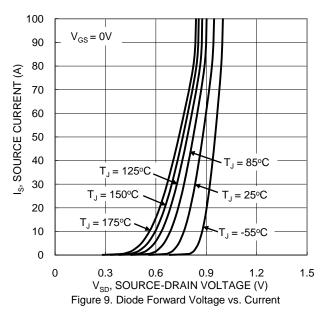
Figure 6. On-Resistance Variation with Junction Temperature

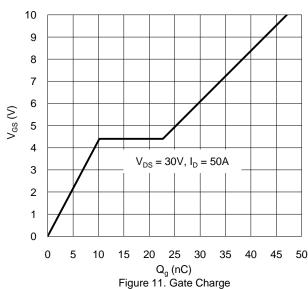












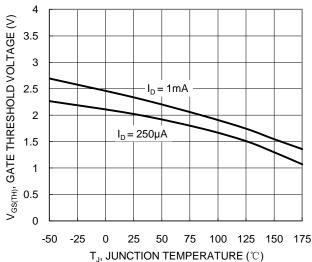
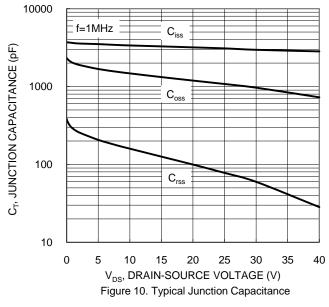
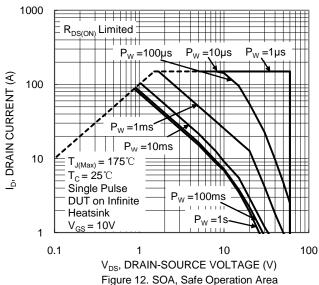


Figure 8. Gate Threshold Variation vs. Junction Temperature







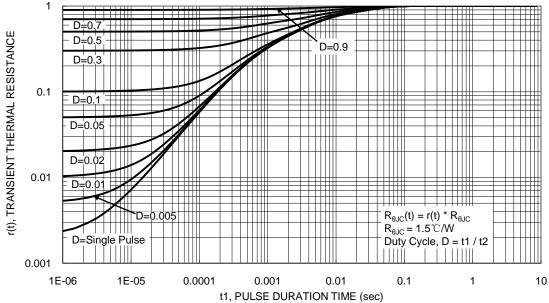


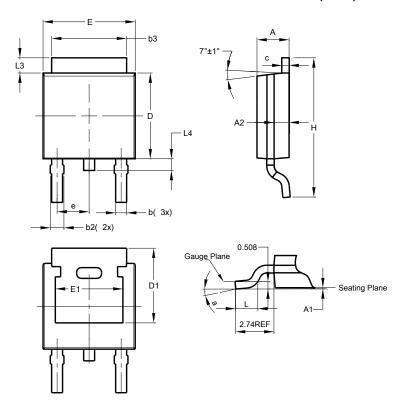
Figure 13. Transient Thermal Resistance



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### **TO252 (DPAK)**

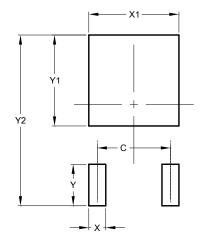


TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
<b>A1</b>	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е -		-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	-		
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	-		
All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### TO252 (DPAK)



Dimensions	Value (in mm)		
С	4.572		
Х	1.060		
X1	5.632		
Υ	2.600		
Y1	5.700		
V2	10.700		



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